

TRIPLE DIFFUSED PLANER TYPE HIGH VOLTAGE,HIGH SPEED SWITCHING

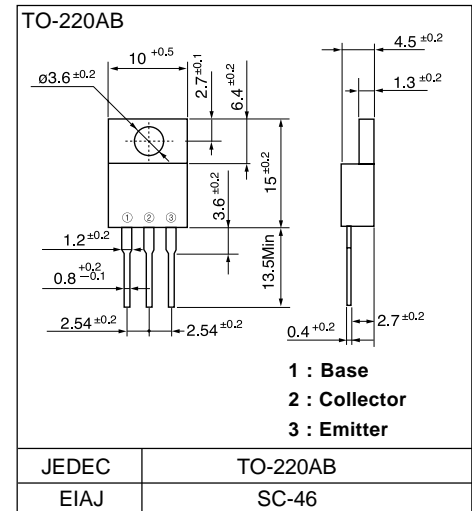
Features

- High voltage,High speed switching
- High reliability

Applications

- Switching regulators
- Ultrasonic generators
- High frequency inverters
- General purpose power amplifiers

Outline Drawings



Maximum ratings and characteristics

Absolute maximum ratings (T_c=25°C unless otherwise specified)

Item	Symbol	Ratings	Unit
Collector-Base voltage	V _{CB0}	450	V
Collector-Emitter voltage	V _{CE0}	400	V
Collector-Emitter voltage	V _{CE0(SUS)}	400	V
Emitter-Base voltage	V _{EB0}	10	V
Collector current	I _C	5	A
Base current	I _B	2	A
Collector power dissipation	P _C	40	W
Operating junction temperature	T _j	+150	°C
Storage temperature	T _{stg}	-55 to +150	°C

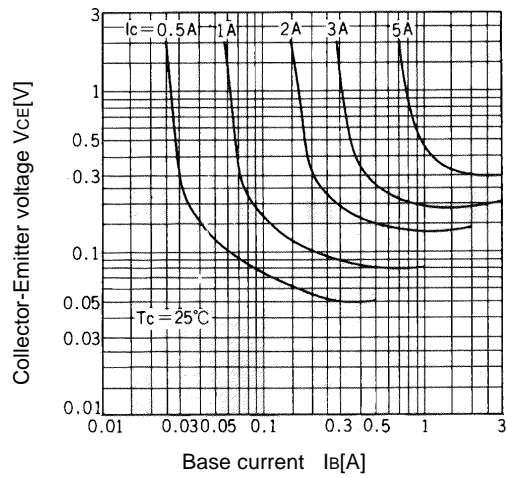
Electrical characteristics (T_c =25°C unless otherwise specified)

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Base voltage	V _{CB0}	I _C = 1mA	450			V
Collector-Emitter voltage	V _{CE0}	I _{CE0} = 10mA	400			V
Collector-Emitter voltage	V _{CE0(SUS)}	I _C = 0.2A	400	-		V
Emitter-Base voltage	V _{EB0}	I _{EB0} = 1mA	10	-		V
Collector-Base leakage current	I _{CB0}	V _{CB0} = 450V		-	0.1	mA
Emitter-Base leakage current	I _{EB0}	V _{EB0} = 10V		-	0.1	mA
D.C. current gain	h _{FE}	I _C = 2A, V _{CE} = 5V	10			
Collector-Emitter saturation voltage	V _{CE(Sat)}	I _C = 2A, I _B = 0.4A			0.8	V
Base-Emitter saturation voltage	V _{BE(Sat)}				1.2	V
*1	t _{on}	I _C = 4A, I _{B1} = 0.8A			1.0	μs
Switching time	t _{stg}	I _{B2} = -1.6A, R _L = 37.5 ohm			2.5	μs
	t _f	P _w = 20μs Duty=<2%			0.5	μs

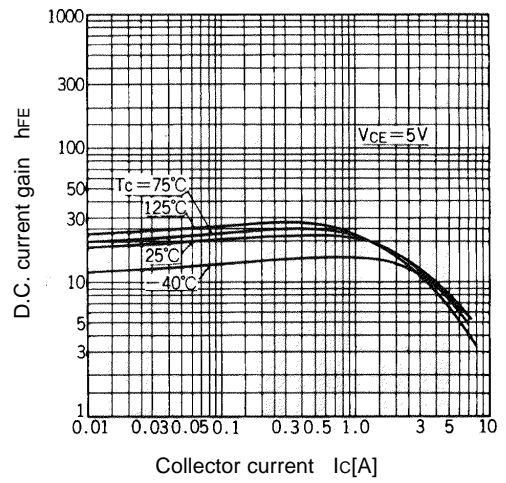
Thermal characteristics

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal resistance	R _{th(j-c)}	Junction to case			3.0	°C/W

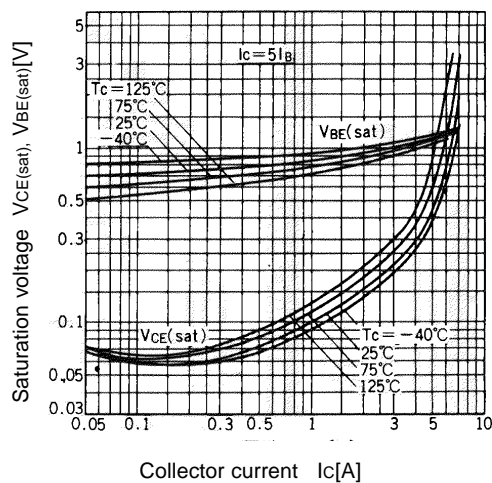
Characteristics



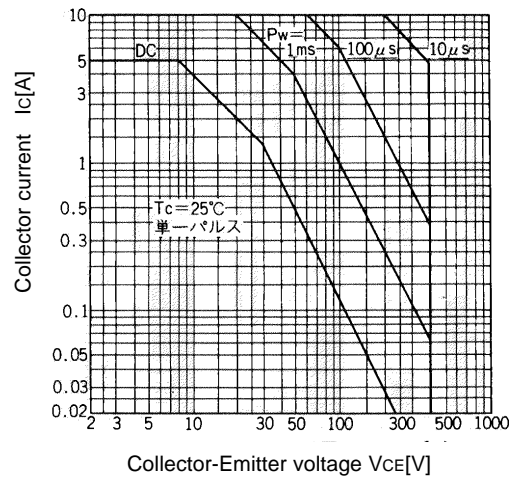
Collector Output Characteristics



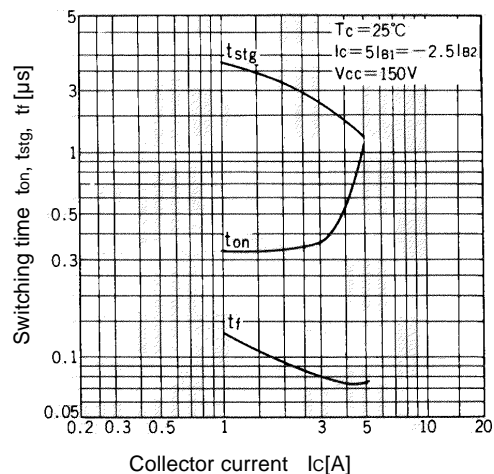
DC Current Gain



Base and Collector Saturation Voltage



Safe Operating Area



Switching Time

*1 Switching Time Test Circuit

